

## BUY69A-BUY69C

High-reliability discrete products and engineering services since 1977

### NPN HIGH VOLTAGE TRANSISTORS

#### FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

#### MAXIMUM RATINGS

Characteristic	Symbol	BUY69A	BUY69B	BUY69C	Unit
Collector-Emitter Voltage (V <sub>BE</sub> = 0)	VCES	1000	800	500	V
Collector-Emitter Voltage	V <sub>CEO</sub>	400	325	200	V
Emitter-Base Voltage	VEBO	8.0		V	
Collector Current – continuous	lc	10		А	
Peak	ICM	15			
Base Current - Peak	IBM	3.0		А	
Total Power Dissipation @ Tc = 25°C	PD	100		W	
Derate above 25°C		0.57		W/°C	
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200		°C	
Thermal Resistance, Junction to Case	R <sub>eJC</sub>	1.75			°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = 25°C unless otherwise specified)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage <sup>(1)</sup>	BUY69A		400	-	-	
(I <sub>B</sub> = 0, I <sub>C</sub> = 100mA, L = 25mH)	BUY69B	V <sub>CEO(sus)</sub>	325	-	-	V
	BUY69C		200	-	-	
Collector-Base Voltage	BUY69A		1000	-	-	
$(I_{C} = 1.0 \text{mA}, I_{E} = 0)$	BUY69B	Vcbo	800	-	-	V
	BUY69C		500	-	-	
Collector Cutoff Current						
$(V_{CE} = 1000V, V_{BE} = 0)$	BUY69A	ICES	-	-	1.0	mA
$(V_{CE} = 800V, V_{BE} = 0)$	BUY69B	ICES	-	-	1.0	IIIA
$(V_{CE} = 500V, V_{BE} = 0)$	BUY69C		-	-	1.0	
Emitter- Base Cutoff Current		I <sub>EBO</sub>				mA
$(V_{EB} = 8.0V, I_{C} = 0)$		IEBO	-	-	1.0	IIIA
ON CHARACTERISTICS (1)						
DC Current Gain		h <sub>fe</sub>				_
(I <sub>C</sub> = 2.5A, V <sub>CE</sub> = 10)		llfe	15	-	-	-
Collector-Emitter Saturation Voltage		Vert				V
(I <sub>C</sub> = 8A, I <sub>B</sub> = 2.5A)		$V_{CE(sat)}$	-	-	3.3	V
Base-Emitter Saturation Voltage		V <sub>B(sat)</sub>				V
(I <sub>C</sub> = 8.0A, I <sub>B</sub> = 2.5A)		VB(sat)	-	-	2.2	v
Current Gain – Bandwidth Product <sup>(2)</sup>		fT				MHz
(I <sub>C</sub> = 0.5A, V <sub>CE</sub> = 10V, f <sub>test</sub> = 1MHz)			10	-	-	111112
SWITCHING CHARACTERISTICS						
Rise Time			tr	-	0.3	
Storage Time V <sub>CC</sub> = 250V, I <sub>C</sub>	• V <sub>CC</sub> = 250V, I <sub>C</sub> = 5A, I <sub>B1</sub> = -I <sub>B2</sub> = 3		ts	-	1.8	μs
Fall Time	7			-	1.0	

Note 1: Pulse test: Pulse width =  $300\mu s$ , duty cycle  $\leq 2.0\%$ .

Note 2:  $f_T = |h_{fe}| * f_{test}$ 



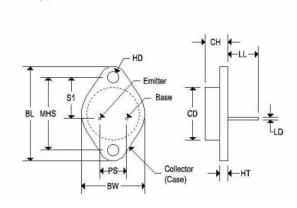
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### MECHANICAL CHARACTERISTICS

Case:	ТО-3
Marking:	Alpha-Numeric
Polarity:	See below



	TO-3					
	Inches		Millimeters			
	Min	Max	Min	Max		
CD	-	0.875		22.220		
СН	0.250	0.380	6.860	9.650		
HT	0.060	0.135	1.520	3.430		
BW	-	1.050		26.670		
HD	0.131	0.188	3.330	4.780		
LD	0.038	0.043	0.970	1.090		
LL	0.312	0.500	7.920	12.700		
BL	1.550	REF	39.370 REF			
MHS	1.177	1.197	29.900	30.400		
PS	0.420	0.440	10.670	11.180		
S1	0.655	0.675	16.640	17.150		

